## Rail-to-Rail High Output Current Quad Operational Amplifiers With Standby Mode and Adjustable Phantom Ground

- Rail-to-rail input and output

■ Low noise: $9 \mathrm{nV} / \sqrt{ } \mathrm{Hz}$
■ Low distortion

- High output current: 80 mA (able to drive $32 \Omega$ loads)
■ High-speed: $4 \mathrm{MHz}, 1.3 \mathrm{~V} / \mu \mathrm{s}$
- Operating from 2.7 V to 12 V

■ Low input offset voltage: $900 \mu \mathrm{~V}$ max. (TS925A)

- Adjustable phantom ground ( $\mathrm{V}_{\mathrm{CC}} / 2$ )
- Standby mode

■ ESD internal protection: 2 kV
■ Latch-up immunity

## Description

The TS925 is a rail-to-rail quad BiCMOS operational amplifier optimized and fully specified for 3 V and 5 V operation.

High output current allows low load impedances to be driven. An internal low impedance phantom ground eliminates the need for an external reference voltage or biasing arrangement.
The TS925 exhibits very low noise, low distortion and high output current making this device an excellent choice for high quality, low voltage or battery operated audio/telecom systems.
The device is stable for capacitive loads up to 500pF. When the STANDBY mode is enabled, the total consumption drops to $6 \mu \mathrm{~A}\left(\mathrm{~V}_{\mathrm{CC}}=3 \mathrm{~V}\right)$.

## Applications

- Headphone amplifier

■ Soundcard amplifier, piezoelectric speaker

- MPEG boards, multimedia systems...

- Cordless telephones and portable communication equipment
- Line driver, buffer
- Instrumentation with low noise as key factor


## Order Codes

| Part Number | Temperature Range | Package | Packing | Marking |
| :---: | :---: | :---: | :---: | :---: |
| TS925IN | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | DIP16 | DIP16 | TS925IN |
| TS925ID/IDT |  | SO-16 | SO-16 | 9251 |
| TS925IPT |  | TSSOP16 | TSSOP16 |  |
| TS925AIN |  | DIP16 | DIP16 | TS925AIN |
| TS925AID |  | SO-16 | SO-16 | 925AI |
| TS925AIPT |  | TSSOP16 | TSSOP16 |  |

## 1 Absolute Maximum Ratings

Table 1. Key parameters and their absolute maximum ratings

| Symbol | Parameter | Condition | Value | Unit |
| :---: | :---: | :---: | :---: | :---: |
| VCC | Supply voltage ${ }^{(1)}$ |  | 14 | V |
| Vid | Differential Input Voltage ${ }^{(2)}$ |  | $\pm 1$ | V |
| $\mathrm{V}_{\mathrm{i}}$ | Input Voltage |  | $\mathrm{V}_{\mathrm{DD}}-0.3$ to $\mathrm{V}_{\mathrm{CC}}+0.3$ | V |
| $\mathrm{T}_{\mathrm{j}}$ | Maximum Junction Temperature |  | 150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{R}_{\text {thja }}$ | Thermal Resistance Junction to Ambient | $\begin{aligned} & \hline \text { SO-16 } \\ & \text { TSSOP16 } \\ & \text { DIP16 } \end{aligned}$ | $\begin{aligned} & 95 \\ & 95 \\ & 63 \end{aligned}$ | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\mathrm{R}_{\text {thic }}$ | Thermal Resistance Junction to Case | $\begin{aligned} & \hline \text { SO-16 } \\ & \text { TSSOP16 } \\ & \text { DIP16 } \end{aligned}$ | $\begin{aligned} & 30 \\ & 25 \\ & 33 \end{aligned}$ | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| ESD | Electro-Static Discharge | HBM <br> Human Body Model ${ }^{(3)}$ | 2 | kV |
|  |  | MM <br> Machine Model ${ }^{(4)}$ | 200 | V |
|  |  | CDM Charged Device Model | 1 | kV |
|  | Output Short Circuit Duration |  | see note ${ }^{(5)}$ |  |
|  | Latch-up Immunity |  | 200 | mA |
|  | Soldering Temperature | 10sec, Pb-free package | 260 | ${ }^{\circ} \mathrm{C}$ |

1. All voltage values, except differential voltage are with respect to network ground terminal.
2. Differential voltages are the non-inverting input terminal with respect to the inverting input terminal. If Vid $> \pm 1 \mathrm{~V}$, the maximum input current must not exceed $\pm 1 \mathrm{~mA}$. In this case (Vid $> \pm 1 \mathrm{~V}$ ) an input serie resistor must be added to limit input current.
3. Human body model, 100 pF discharged through a $1.5 \mathrm{k} \Omega$ resistor into pin of device.
4. Machine model ESD, a 200 pF cap is charged to the specified voltage, then discharged directly into the IC with no external series resistor (internal resistor $<5 \Omega$ ), into pin to pin of device.
5. There is no short-circuit protection inside the device: short-circuits from the output to $V_{c c}$ can cause excessive heating. The maximum output current is approximately 80 mA , independent of the magnitude of $V_{c c}$. Destructive dissipation can result from simultaneous short-circuits on all amplifiers.

Table 2. Operating conditions

| Symbol | Parameter | Value | Unit |
| :---: | :--- | :---: | :---: |
| $\mathrm{V}_{\mathrm{CC}}$ | Supply Voltage | 2.7 to 12 | V |
| $\mathrm{~V}_{\mathrm{icm}}$ | Common Mode Input Voltage Range | $\mathrm{V}_{\mathrm{DD}}-0.2$ to $\mathrm{V}_{\mathrm{CC}}+0.2$ | V |
| $\mathrm{~T}_{\text {oper }}$ | Operating Free Air Temperature Range | -40 to +125 | ${ }^{\circ} \mathrm{C}$ |

## 2 Electrical Characteristics

Table 3. Electrical characteristics for $\mathrm{V}_{\mathrm{CC}}=3 \mathrm{~V}, \mathrm{~V}_{\mathrm{DD}}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{icm}}=\mathrm{V}_{\mathrm{CC}} / 2, \mathrm{R}_{\mathrm{L}}$ connected to $\mathrm{V}_{\mathrm{CC}} / 2, \mathrm{~T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$ (unless otherwise specified)

| Symbol | Parameter | Conditions | Min. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {io }}$ | Input Offset Voltage | $\begin{aligned} & \text { at } \mathrm{T}_{\mathrm{amb}}=+25^{\circ} \mathrm{C} \\ & \mathrm{TS} 925 \\ & \mathrm{TS} 925 \mathrm{~A} \\ & \text { at } \mathrm{T}_{\text {min. }} \leq \mathrm{T}_{\mathrm{amb}} \leq \mathrm{T}_{\text {max }}: \\ & \mathrm{TS} 925 \\ & \mathrm{TS} 925 \mathrm{~A} \end{aligned}$ |  |  | $\begin{gathered} 3 \\ 0.9 \\ 5 \\ 5 \\ 1.8 \end{gathered}$ | mV |
| DV ${ }_{\text {io }}$ | Input Offset Voltage Drift |  |  | 2 |  | $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ |
| $\mathrm{I}_{10}$ | Input Offset Current | $\mathrm{V}_{\text {out }}=1.5 \mathrm{~V}$ |  | 1 | 30 | nA |
| $\mathrm{l}_{\text {ib }}$ | Input Bias Current | $\mathrm{V}_{\text {out }}=2.5 \mathrm{~V}$ |  | 15 | 100 | nA |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega \\ & \mathrm{R}_{\mathrm{L}}=600 \Omega \\ & \mathrm{R}_{\mathrm{L}}=32 \Omega \end{aligned}$ | $\begin{aligned} & 2.90 \\ & 2.87 \end{aligned}$ | 2.63 |  | V |
| $\mathrm{V}_{\mathrm{OL}}$ | Low Level Output Voltage | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega \\ & \mathrm{R}_{\mathrm{L}}=600 \Omega \\ & \mathrm{R}_{\mathrm{L}}=32 \Omega \end{aligned}$ |  | 180 | $\begin{gathered} 50 \\ 100 \end{gathered}$ | mV |
| $\mathrm{A}_{\mathrm{vd}}$ | Large Signal Voltage Gain | $\begin{aligned} & \mathrm{V}_{\text {out }}=2 \mathrm{~V}_{\text {pk-pk }} \\ & \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega \\ & \mathrm{R}_{\mathrm{L}}=600 \Omega \\ & \mathrm{R}_{\mathrm{L}}=32 \Omega \end{aligned}$ |  | $\begin{gathered} 200 \\ 35 \\ 16 \end{gathered}$ |  | $\mathrm{V} / \mathrm{mV}$ |
| GBP | Gain Bandwidth Product | $\mathrm{R}_{\mathrm{L}}=600 \Omega$ |  | 4 |  | MHz |
| CMR | Common Mode Rejection Ratio |  | 60 | 80 |  | dB |
| SVR | Supply Voltage Rejection Ratio | $\mathrm{V}_{\text {cc }}=2.7$ to 3.3 V | 60 | 85 |  | dB |
| $I_{0}$ | Output Short-Circuit Current |  | 50 | 80 |  | mA |
| SR | Slew Rate |  | 0.7 | 1.3 |  | V/ $\mu \mathrm{s}$ |
| Pm | Phase Margin at Unit Gain | $\mathrm{R}_{\mathrm{L}}=600 \Omega, \mathrm{C}_{\mathrm{L}}=100 \mathrm{pF}$ |  | 68 |  | Degrees |
| GM | Gain Margin | $\mathrm{R}_{\mathrm{L}}=600 \Omega, \mathrm{C}_{\mathrm{L}}=100 \mathrm{pF}$ |  | 12 |  | dB |
| $e_{n}$ | Equivalent Input Noise Voltage | $\mathrm{f}=1 \mathrm{kHz}$ |  | 9 |  | $\frac{n V}{\sqrt{H z}}$ |
| THD | Total Harmonic Distortion | $\begin{aligned} & V_{\text {out }}=2 V_{p k-p k}, \\ & f=1 \mathrm{kHz}, A_{v}=1, \\ & R_{L}=600 \Omega \end{aligned}$ |  | 0.01 |  | \% |
| $\mathrm{C}_{\text {s }}$ | Channel Separation |  |  | 120 |  | dB |

Table 4. Global circuit

| Symbol | Parameter | Conditions | Min. | Typ | Max. | Unit |
| :---: | :--- | :--- | :---: | :---: | :---: | :---: |
| $\mathrm{I}_{\mathrm{CC}}$ | Total Supply Current | No load, $\mathrm{V}_{\text {out }}=\mathrm{V}_{\mathrm{cc} / 2}$ |  | 5 | 7 | mA |
| $\mathrm{I}_{\text {stby }}$ | Total Supply Current in STANDBY | Pin 9 connected to $\mathrm{V}_{\text {cc- }}$ |  | 6 |  | $\mu \mathrm{~A}$ |
| $\mathrm{~V}_{\text {enstby }}$ | Pin 9 Voltage to enable the <br> STANDBY mode${ }^{(1)}$ | at $\mathrm{T}_{\mathrm{amb}}=+25^{\circ} \mathrm{C}$ <br> at $\mathrm{T}_{\min } \leq \mathrm{T}_{\mathrm{amb}} \leq \mathrm{T}_{\max }$ |  |  | 0.3 <br> 0.4 | V |
| $\mathrm{~V}_{\text {distby }}$ | Pin 9 Voltage to disable the <br> STANDBY mode${ }^{(1)}$ | at $\mathrm{T}_{\mathrm{amb}}=+25^{\circ} \mathrm{C}$ <br> at $\mathrm{T}_{\min } \leq \mathrm{T}_{\mathrm{amb}} \leq \mathrm{T}_{\max }$ | 1.1 <br> 1 |  |  | V |

1. The STANDBY mode is currently enabled when Pin 9 is GROUNDED and disabled when Pin 9 is left OPEN.

Table 5. Phantom ground

| Symbol | Parameter | Conditions | Min. | Typ | Max. | Unit |
| :---: | :--- | :--- | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {pg }}$ | Phantom Ground Output Voltage | No Output Current | $\mathrm{V}_{\mathrm{cc} / 2}$ <br> $-5 \%$ | $\mathrm{V}_{\mathrm{cc} / 2}$ | $\mathrm{V}_{\mathrm{cc} / 2}$ <br> $+5 \%$ | V |
| $\mathrm{I}_{\text {pgsc }}$ | Phantom Ground Output Short <br> Circuit Current - Sourced |  | 12 | 18 |  | mA |
| $\mathrm{Z}_{\mathrm{pg}}$ | Phantom Ground Impedance | DC to 20 kHz |  | 3 |  | $\Omega$ |
| $\mathrm{E}_{\mathrm{npg}}$ | Phantom Ground Output Voltage <br> Noise | $\mathrm{f}=1 \mathrm{kHz}$ <br> $\mathrm{C}_{\mathrm{dec}}=100 \mathrm{pF}$ <br> $\mathrm{C}_{\mathrm{dec}}=1 \mathrm{nF}$ <br> $\mathrm{C}_{\mathrm{dec}}=10 \mathrm{nF}^{(1)}$ | 200 <br> 40 <br> 17 |  | $\frac{\mathrm{nV}}{\sqrt{\mathrm{Hz}}}$ |  |
| $\mathrm{I}_{\text {pgsk }}$ | Phantom Ground Output Short <br> Circuit Current - Sinked |  | 12 | 18 |  | mA |

1. $\mathrm{C}_{\mathrm{dec}}$ is the decoupling capacitor on Pin9.

Table 6. Electrical characteristics for $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{DD}}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{icm}}=\mathrm{V}_{\mathrm{Cc}} / 2, \mathrm{R}_{\mathrm{L}}$ connected to $\mathrm{V}_{\mathrm{CC}} / 2, \mathrm{~T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$ (unless otherwise specified)

| Symbol | Parameter | Conditions | Min. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {io }}$ | Input Offset Voltage | $\begin{aligned} & \text { at } \mathrm{T}_{\mathrm{amb}}=+25^{\circ} \mathrm{C}: \\ & \text { TS925 } \\ & \text { TS925A } \\ & \text { at } \mathrm{T}_{\text {min. }} \leq \mathrm{T}_{\text {amb }} \leq \mathrm{T}_{\text {max }} \text { : } \\ & \text { TS925 } \\ & \text { TS925A } \end{aligned}$ |  |  | $\begin{gathered} 3 \\ 0.9 \\ \\ 5 \\ 1.8 \end{gathered}$ | mV |
| DV ${ }_{\text {io }}$ | Input Offset Voltage Drift |  |  | 2 |  | $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ |
| $\mathrm{I}_{\mathrm{i}}$ | Input Offset Current | $\mathrm{V}_{\text {out }}=2.5 \mathrm{~V}$ |  | 1 | 30 | nA |
| $\mathrm{l}_{\text {ib }}$ | Input Bias Current | $\mathrm{V}_{\text {out }}=2.5 \mathrm{~V}$ |  | 15 | 100 | nA |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega \\ & \mathrm{R}_{\mathrm{L}}=600 \Omega \\ & \mathrm{R}_{\mathrm{L}}=32 \Omega \end{aligned}$ | $\begin{aligned} & 4.90 \\ & 4.85 \end{aligned}$ | 4.4 |  | V |
| $\mathrm{V}_{\text {OL }}$ | Low Level Output Voltage | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega \\ & \mathrm{R}_{\mathrm{L}}=600 \Omega \\ & \mathrm{R}_{\mathrm{L}}=32 \Omega \end{aligned}$ |  | 300 | $\begin{gathered} 50 \\ 120 \end{gathered}$ | mV |
| $\mathrm{A}_{\mathrm{vd}}$ | Large Signal Voltage Gain | $\begin{aligned} & \mathrm{V}_{\text {out }}=2 \mathrm{~V}_{\text {pk-pk }} \\ & \mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \\ & \mathrm{R}_{\mathrm{L}}=600 \Omega \\ & \mathrm{R}_{\mathrm{L}}=32 \Omega \end{aligned}$ |  | $\begin{gathered} 200 \\ 40 \\ 17 \end{gathered}$ |  | V/mV |
| GBP | Gain Bandwidth Product | $R_{L}=600 \Omega$ |  | 4 |  | MHz |
| CMR | Common Mode Rejection Ratio |  | 60 | 80 |  | dB |
| SVR | Supply Voltage Rejection Ratio | $\mathrm{V}_{\mathrm{cC}}=3$ to 5 V | 60 | 85 |  | dB |
| Io | Output Short-Circuit Current |  | 50 | 80 |  | mA |
| SR | Slew Rate |  | 0.7 | 1.3 |  | V/us |
| Pm | Phase Margin at Unit Gain | $\mathrm{R}_{\mathrm{L}}=600 \Omega, \mathrm{C}_{\mathrm{L}}=100 \mathrm{pF}$ |  | 68 |  | Degrees |
| GM | Gain Margin | $\mathrm{R}_{\mathrm{L}}=600 \Omega, \mathrm{C}_{\mathrm{L}}=100 \mathrm{pF}$ |  | 12 |  | dB |
| $\mathrm{e}_{\mathrm{n}}$ | Equivalent Input Noise Voltage | $\mathrm{f}=1 \mathrm{kHz}$ |  | 9 |  | $\frac{\mathrm{nV}}{\sqrt{\mathrm{Hz}}}$ |
| THD | Total Harmonic Distortion | $\begin{aligned} & V_{\text {out }}=2 V_{\text {pk-pk }}, f=1 \mathrm{kHz}, \\ & A_{V}=1, R_{L}=600 \Omega \end{aligned}$ |  | 0.01 |  | \% |
| $\mathrm{C}_{\text {s }}$ | Channel Separation |  |  | 120 |  | dB |

Table 7. Global circuit

| Symbol | Parameter | Conditions | Min. | Typ | Max. | Unit |
| :---: | :--- | :--- | :---: | :---: | :---: | :---: |
| $\mathrm{I}_{\mathrm{CC}}$ | Total Supply Current | No load, $\mathrm{V}_{\text {out }}=\mathrm{V}_{\mathrm{cc} / 2}$ |  | 6 | 8 | mA |
| $\mathrm{I}_{\text {stby }}$ | Total Supply Current in <br> STANDBY | Pin 9 connected to $\mathrm{V}_{\mathrm{cC}}$ |  |  |  |  |

1. the STANDBY mode is currently enabled when Pin 9 is GROUNDED and disabled when Pin 9 is left OPEN.

Table 8. Phantom ground

| Symbol | Parameter | Conditions | Min. | Typ | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{pg}}$ | Phantom Ground Output Voltage | No Output Current | $\begin{aligned} & V_{\mathrm{cc} / 2} \\ & -5 \% \end{aligned}$ | $\mathrm{V}_{\mathrm{cc} / 2}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{cc} / 2} \\ & +5 \% \end{aligned}$ | V |
| $\mathrm{I}_{\text {pgsc }}$ | Phantom Ground Output Short Circuit Current - Sourced |  | 12 | 18 |  | mA |
| $\mathrm{Z}_{\mathrm{pg}}$ | Phantom Ground Impedance | DC to 20kHz |  | 3 |  | $\Omega$ |
| $\mathrm{E}_{\mathrm{npg}}$ | Phantom Ground Output Voltage Noise | $\begin{aligned} & f=1 \mathrm{kHz} \\ & C_{\text {dec }}=100 \mathrm{pF} \\ & C_{\text {dec }}=1 \mathrm{nF}^{(1)} \\ & C_{\text {dec }}=10 \mathrm{~F}^{(1)} \end{aligned}$ |  | $\begin{gathered} 200 \\ 40 \\ 17 \end{gathered}$ |  | $\frac{\mathrm{nV}}{\sqrt{\mathrm{Hz}}}$ |
| $\mathrm{l}_{\text {pgsk }}$ | Phantom Ground Output Short Circuit Current - Sinked |  | 12 | 18 |  | mA |

1. $\mathrm{C}_{\mathrm{dec}}$ is the decoupling capacitor on Pin9.

Figure 1. Input offset voltage distribution


Figure 3. Supply current/amplifier vs. temperature


Figure 5. Output short circuit current vs. output voltage


Figure 2. Total supply current vs. supply voltage with no load


Figure 4. Output short circuit current vs. output voltage


Figure 6. Output short circuit current vs. output voltage


Figure 7. Output short circuit current vs. temperature


Figure 9. Distortion + noise vs. frequency


Figure 11. THD + noise vs. frequency


Figure 8. Voltage gain and phase vs. frequency


Figure 10. THD + noise vs. frequency


Figure 12. THD + noise vs. frequency


Figure 13. Equivalent input noise vs. frequency


Figure 15. Phantom ground short circuit output current vs. phantom ground output voltage


Figure 14. Total supply current vs. standby input voltage


## 3 Using the TS925 as a preamplifier and speaker driver

The TS925 is an input/output rail-to-rail quad BiCMOS operational amplifier. It is able to operate with low supply voltages (2.7V) and to drive low output loads such as $32 \Omega$.

As an illustration of these features, the following technical note highlights many of the advantages of the device in a global audio application.

### 3.1 Application circuit

Figure 16 shows two operators (A1, A4) used in a preamplifier configuration, and the two others in a push-pull configuration driving a headset. The phantom ground is used as a common reference level ( $\mathrm{V}_{\mathrm{CC}} / 2$ ).

The power supply is delivered from two LR6 batteries ( $2 \times 1.5 \mathrm{~V}$ nominal).

## Preamplifier

The operators A1 and A4 are wired with a non-inverting gain of respectively:

- A1\# (R4/(R3+R17))
- A4\# R6/R5

With the following values chosen:

- $\mathrm{R} 4=22 \mathrm{k} \Omega-\mathrm{R} 3=50 \Omega-\mathrm{R} 17=1.2 \mathrm{k} \Omega$
- $\mathrm{R} 6=47 \mathrm{k} \Omega-\mathrm{R} 5=1.2 \mathrm{k} \Omega$,

The gain of the preamplifier chain is therefore equal to 58 dB .
Alternatively, the gain of A1 can be adjusted by choosing a JFET transistor Q1 instead of R17.
This JFET voltage controlled resistor arrangement forms an automatic level control (ALC) circuit, useful in many microphone preamplifier applications. The mean rectified peak level of the output signal envelope is used to control the preamplifier gain.

Figure 16. Electrical schematic


## Headphone amplifier

The operators A2 and A3 are organized in a push-pull configuration with a gain of 5 . The stereo inputs can be connected to a CD-player and the TS925 can directly drive the head-phone speakers. This configuration shows the ability of the circuit to drive $32 \Omega$ load with a maximum output swing and high fidelity suitable for sound and music.

Figure 19 shows the available signal swing at the headset outputs: two other rail-to-rail competitor parts are employed in the same circuit for comparison (note the much reduced clipping level and crossover distortion).

Figure 17. Frequency response of the global preamplifier chain


Figure 19. Maximum voltage swing at headphone outputs $\left(R_{L}=32 \Omega\right)$


Figure 18. Voltage noise density vs.
frequency at preamplifier output


Figure 20. THD + noise vs. frequency (headphone outputs)


## 4 Package Mechanical Data

In order to meet environmental requirements, ST offers these devices in ECOPACK ${ }^{\circledR}$ packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

### 4.1 DIP16 Package

| Plastic DIP-16 (0.25) MECHANICAL DATA |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| DIM. | mm. |  |  | inch |  |  |
|  | MIN. | TYP | MAX. | MIN. | TYP. | MAX. |
| a1 | 0.51 |  |  | 0.020 |  |  |
| B | 0.77 |  | 1.65 | 0.030 |  | 0.065 |
| b |  | 0.5 |  |  | 0.020 |  |
| b1 |  | 0.25 |  |  | 0.010 |  |
| D |  |  | 20 |  |  | 0.787 |
| E |  | 8.5 |  |  | 0.335 |  |
| e |  | 2.54 |  |  | 0.100 |  |
| e3 |  | 17.78 |  |  | 0.700 |  |
| F |  |  | 7.1 |  |  | 0.280 |
| 1 |  |  | 5.1 |  |  | 0.201 |
| L |  | 3.3 |  |  | 0.130 |  |
| z |  |  | 1.27 |  |  | 0.050 |



### 4.2 SO-16 Package

SO-16 MECHANICAL DATA

| DIM. | mm. |  |  | inch |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | MIN. | TYP | MAX. | MIN. | TYP. | MAX. |
| A |  |  | 1.75 |  |  | 0.068 |
| a1 | 0.1 |  | 0.2 | 0.004 |  | 0.008 |
| a2 |  |  | 1.65 |  |  | 0.064 |
| b | 0.35 |  | 0.46 | 0.013 |  | 0.018 |
| b1 | 0.19 |  | 0.25 | 0.007 |  | 0.010 |
| C |  | 0.5 |  |  | 0.019 |  |
| c1 |  |  |  |  |  |  |
| D | 9.8 |  | 10 | 0.385 |  | 0.393 |
| E | 5.8 |  | 6.2 | 0.228 |  | 0.244 |
| e |  | 1.27 |  |  | 0.050 |  |
| e3 |  | 8.89 |  |  | 0.350 |  |
| F | 3.8 |  | 4.0 | 0.149 |  | 0.157 |
| G | 4.6 |  | 5.3 | 0.181 |  | 0.208 |
| L | 0.5 |  | 1.27 | 0.019 |  | 0.050 |
| M |  |  | 0.62 |  |  | 0.024 |
| S | 8 * (max.) |  |  |  |  |  |



### 4.3 TSSOP16 Package

## TSSOP16 MECHANICAL DATA

| DIM. | mm. |  |  | inch |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | MIN. | TYP | MAX. | MIN. | TYP. | MAX. |
| A |  |  | 1.2 |  |  | 0.047 |
| A1 | 0.05 |  | 0.15 | 0.002 | 0.004 | 0.006 |
| A2 | 0.8 | 1 | 1.05 | 0.031 | 0.039 | 0.041 |
| b | 0.19 |  | 0.30 | 0.007 |  | 0.012 |
| c | 0.09 |  | 0.20 | 0.004 |  | 0.0079 |
| D | 4.9 | 5 | 5.1 | 0.193 | 0.197 | 0.201 |
| E | 6.2 | 6.4 | 6.6 | 0.244 | 0.252 | 0.260 |
| E1 | 4.3 | 4.4 | 4.48 | 0.169 | 0.173 | 0.176 |
| e |  | 0.65 BSC |  |  | 0.0256 BSC |  |
| K | $0^{\circ}$ |  | $8^{\circ}$ | 0 |  |  |
| L | 0.45 | 0.60 | 0.75 | 0.018 | 0.024 | 0.030 |



## 5 Revision History

| Date | Revision | Changes |
| :---: | :---: | :--- |
| Feb. 2001 | 1 | Initial release - Product in full production. |
| Nov. 2005 | 2 | The following changes were made in this revision: <br> - Chapter on Macromodels removed from the datasheet. <br> - Data updated in Table 3. on page 4. <br> - Data in tables in Electrical Characteristics on page 4 reformatted for <br> easier use. <br> - Minor grammatical and formatting changes throughout. |

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